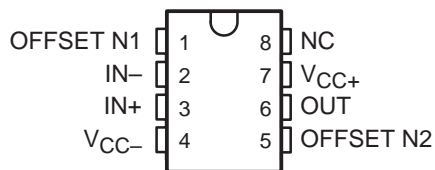


TL061, TL061A, TL061B, TL062, TL062A TL062B, TL064, TL064A, TL064B LOW-POWER JFET-INPUT OPERATIONAL AMPLIFIERS

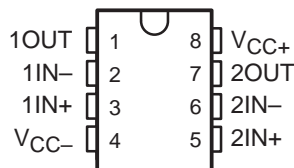
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- Very Low Power Consumption
- Typical Supply Current . . . 200 μ A (Per Amplifier)
- Wide Common-Mode and Differential Voltage Ranges
- Low Input Bias and Offset Currents
- Common-Mode Input Voltage Range Includes V_{CC+}
- Output Short-Circuit Protection
- High Input Impedance . . . JFET-Input Stage
- Internal Frequency Compensation
- Latch-Up-Free Operation
- High Slew Rate . . . 3.5 V/ μ s Typ

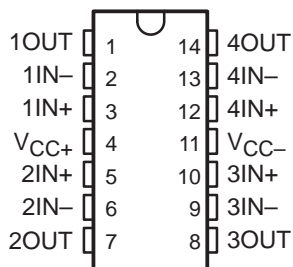
TL061, TL061A . . . D, P, OR PS PACKAGE
TL061B . . . P PACKAGE
(TOP VIEW)



TL062 . . . D, JG, P, PS, OR PW PACKAGE
TL062A . . . D, P, OR PS PACKAGE
TL062B . . . D OR P PACKAGE
(TOP VIEW)

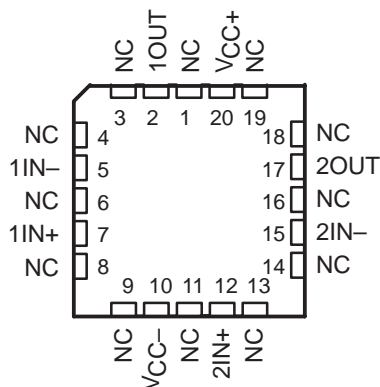


TL064 . . . D, J, N, NS, PW, OR W PACKAGE
TL064A, TL064B . . . D OR N PACKAGE
(TOP VIEW)

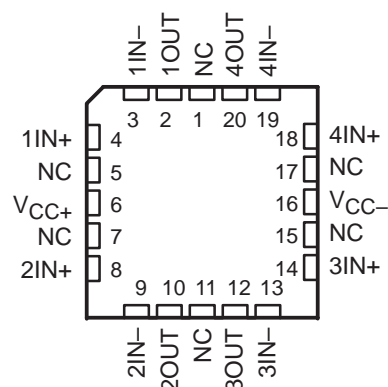


NC – No internal connection

TL062 . . . FK PACKAGE
(TOP VIEW)



TL064 . . . FK PACKAGE
(TOP VIEW)



description/ordering information

The JFET-input operational amplifiers of the TL06_ series are designed as low-power versions of the TL08_ series amplifiers. They feature high input impedance, wide bandwidth, high slew rate, and low input offset and input bias currents. The TL06_ series feature the same terminal assignments as the TL07_ and TL08_ series. Each of these JFET-input operational amplifiers incorporates well-matched, high-voltage JFET and bipolar transistors in an integrated circuit.

The C-suffix devices are characterized for operation from 0°C to 70°C. The I-suffix devices are characterized for operation from -40°C to 85°C, and the M-suffix devices are characterized for operation over the full military temperature range of -55°C to 125°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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**TL061, TL061A, TL061B, TL062, TL062A
 TL062B, TL064, TL064A, TL064B
 LOW-POWER JFET-INPUT OPERATIONAL AMPLIFIERS**

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description/ordering information (continued)

ORDERING INFORMATION

TA	V _{IO} MAX AT 25°C	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING	
0°C to 70°C	15 mV	PDIP (P)	Tube of 50	TL061CP	TL061CP	
				TL062CP	TL062CP	
		PDIP (N)	Tube of 25	TL064CN	TL064CN	
		SOIC (D)	Tube of 75	TL061CD	TL061C	
				Reel of 2500		TL061CDR
			Tube of 75	TL062CD	TL062C	
				Reel of 2500		TL062CDR
			Tube of 50	TL064CD	TL064C	
				Reel of 2500		TL064CDR
		SOP (PS)	Reel of 2000	TL061CPSR	T061	
		TL062CPSR		T062		
		SOP (NS)	Reel of 2000	TL064CNSR	TL064	
		TSSOP (PW)	Tube of 150	TL062CPW	T062	
				Reel of 2000		TL062CPWR
			Tube of 90	TL064CPW	T064	
				Reel of 2000		TL064CPWR
		6 mV	PDIP (P)	Tube of 50	TL061ACP	TL061ACP
					TL062ACP	TL062ACP
	PDIP (N)		Tube of 25	TL064ACN	TL064ACN	
				SOIC (D)	Tube of 75	TL061ACD
	Reel of 2500		TL061ACDR			
	Tube of 75		TL062ACD	062AC		
			Reel of 2500		TL062ACDR	
	Tube of 50		TL064ACD	TL064AC		
			Reel of 2500		TL064ACDR	
	SOP (PS)		Reel of 2000	TL061ACPSR	T061A	
				TL062ACPSR	T062A	
	3 mV		PDIP (P)	Tube of 50	TL061BCP	TL061BCP
		TL062BCP			TL062BCP	
		PDIP (N)	Tube of 25	TL064BCN	TL064BCN	
SOIC (D)		Tube of 75	TL062BCD	062BC		
			Reel of 2500		TL062BCDR	
Tube of 50		TL064BCD	TL064BC			
	Reel of 2500	TL064BCDR				

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



TL061, TL061A, TL061B, TL062, TL062A
 TL062B, TL064, TL064A, TL064B
LOW-POWER JFET-INPUT OPERATIONAL AMPLIFIERS

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description/ordering information (continued)

ORDERING INFORMATION (continued)

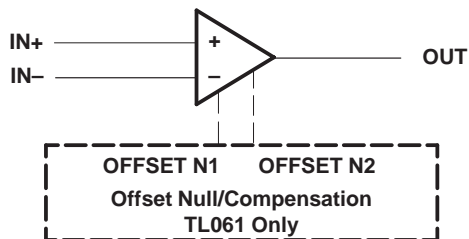
T _A	V _{IOMAX} AT 25°C	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	6 mV	PDIP (P)	Tube of 50	TL061IP	TL061IP
				TL062IP	TL062IP
		PDIP (N)	Tube of 25	TL064IN	TL064IN
				SOIC (D)	Tube of 75
		Reel of 2000	TL061IDR		
		Tube of 75	TL062ID		TL062I
		Reel of 2000	TL062IDR		
		Tube of 50	TL064ID	TL064I	
Reel of 2500	TL064IDR				
–55°C to 125°C	6 mV	CDIP (JG)	Tube of 50	TL062MJG	TL062MJG
		LCCC (FK)	Tube of 55	TL062MFK	TL062MFK
	9 mV	CDIP (J)	Tube of 25	TL064MJ	TL064MJ
		CFP (W)	Tube of 150	TL064MW	TL064MW
		LCCC (FK)	Tube of 55	TL064MFK	TL064MFK

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

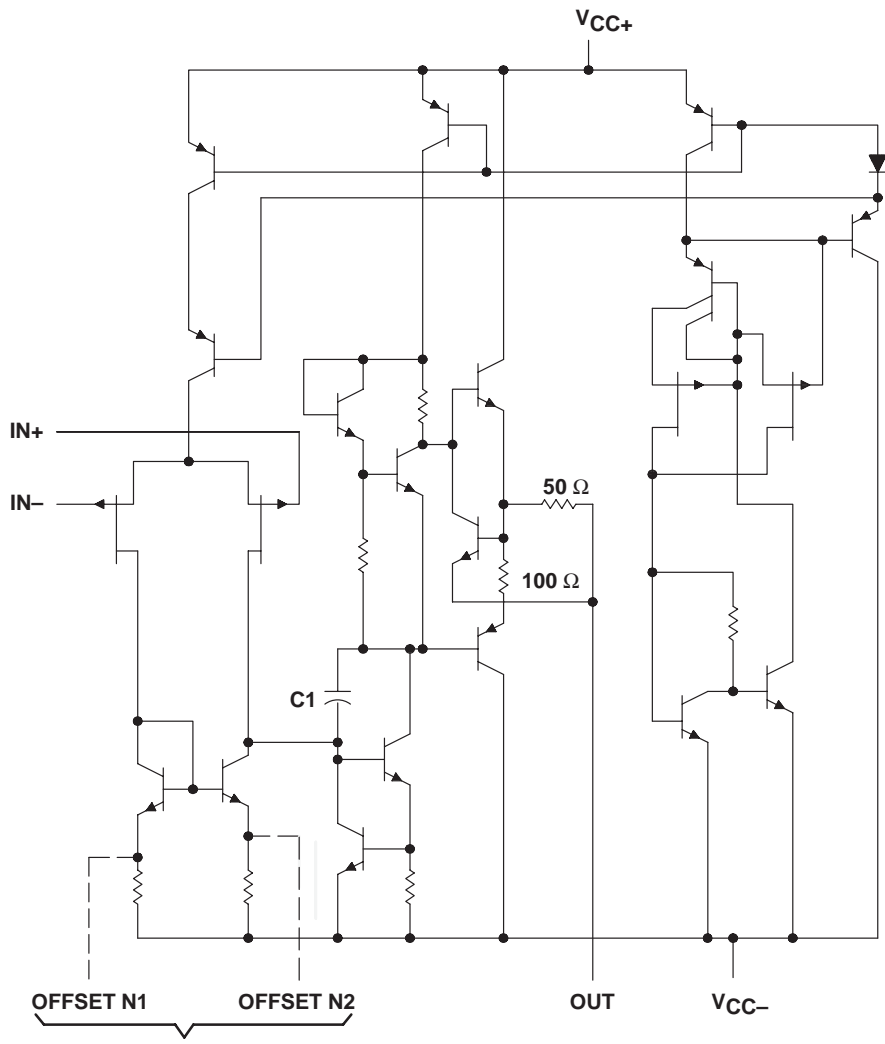
**TL061, TL061A, TL061B, TL062, TL062A
 TL062B, TL064, TL064A, TL064B
 LOW-POWER JFET-INPUT OPERATIONAL AMPLIFIERS**

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symbol (each amplifier)



schematic (each amplifier)



TL061 Only

C1 = 10 pF on TL061, TL062, and TL064
 Component values shown are nominal.



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**TL061, TL061A, TL061B, TL062, TL062A
TL062B, TL064, TL064A, TL064B
LOW-POWER JFET-INPUT OPERATIONAL AMPLIFIERS**

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

		TL06_C TL06_AC TL06_BC	TL06_I	TL06_M	UNIT
Supply voltage, V_{CC+} (see Note 1)		18	18	18	V
Supply voltage, V_{CC-} (see Note 1)		-18	-18	-18	V
Differential input voltage, V_{ID} (see Note 2)		± 30	± 30	± 30	V
Input voltage, V_I (see Notes 1 and 3)		± 15	± 15	± 15	V
Duration of output short circuit (see Note 4)		Unlimited	Unlimited	Unlimited	
Package thermal impedance, θ_{JA} (see Notes 5 and 6)	D (8-pin) package	97	97		°C/W
	D (14-pin) package	86	86		
	N package	80	80		
	NS package	76	76		
	P package	85	85		
	PS package	95	95		
	PW (8-pin) package	149	149		
Package thermal impedance, θ_{JC} (see Notes 7 and 8)	FK package			5.61	°C/W
	J package			15.05	
	JG package			14.5	
	W package			14.65	
Operating virtual junction temperature, T_J		150	150	150	°C
Case temperature for 60 seconds	FK package			260	°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	J, JG, U, or W package			300	°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D, N, NS, P, PS, or PW package	260	260		°C
Storage temperature range, T_{stg}		-65 to 150	-65 to 150	-65 to 150	°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
- All voltage values except differential voltages are with respect to the midpoint between V_{CC+} and V_{CC-} .
 - Differential voltages are at $IN+$ with respect to $IN-$.
 - The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
 - The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.
 - Maximum power dissipation is a function of $T_J(\max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
 - The package thermal impedance is calculated in accordance with JESD 51-7.
 - Maximum power dissipation is a function of $T_J(\max)$, θ_{JC} , and T_C . The maximum allowable power dissipation at any allowable case temperature is $P_D = (T_J(\max) - T_C)/\theta_{JC}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
 - The package thermal impedance is calculated in accordance with MIL-STD-883.

**TL061, TL061A, TL061B, TL062, TL062A
TL062B, TL064, TL064A, TL064B
LOW-POWER JFET-INPUT OPERATIONAL AMPLIFIERS**

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electrical characteristics, $V_{CC\pm} = \pm 15\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	TL061C TL062C TL064C			TL061AC TL062AC TL064AC			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 0,$ $R_S = 50\ \Omega$	$T_A = 25^\circ\text{C}$		3	15	$T_A = 25^\circ\text{C}$		mV
		$T_A = \text{Full range}$		20		7.5		
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage	$V_O = 0, R_S = 50\ \Omega,$ $T_A = \text{Full range}$	10			10			$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current	$V_O = 0$	$T_A = 25^\circ\text{C}$		5	200	$T_A = 25^\circ\text{C}$		pA
		$T_A = \text{Full range}$		5		3		nA
I_{IB} Input bias current‡	$V_O = 0$	$T_A = 25^\circ\text{C}$		30	400	$T_A = 25^\circ\text{C}$		pA
		$T_A = \text{Full range}$		10		7		nA
V_{ICR} Common-mode input voltage range	$T_A = 25^\circ\text{C}$	± 11	-12 to 15	± 11	-12 to 15			V
V_{OM} Maximum peak output voltage swing	$R_L = 10\ \text{k}\Omega, T_A = 25^\circ\text{C}$	± 10	± 13.5	± 10	± 13.5			V
	$R_L \geq 10\ \text{k}\Omega, T_A = \text{Full range}$	± 10		± 10				
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10\ \text{V},$ $R_L \geq 10\ \text{k}\Omega$	$T_A = 25^\circ\text{C}$		3	6	$T_A = 25^\circ\text{C}$		V/mV
		$T_A = \text{Full range}$		3		4		
B_1 Unity-gain bandwidth	$R_L = 10\ \text{k}\Omega, T_A = 25^\circ\text{C}$	1			1			MHz
r_i Input resistance	$T_A = 25^\circ\text{C}$	10^{12}			10^{12}			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0,$ $R_S = 50\ \Omega, T_A = 25^\circ\text{C}$	70	86	80	86			dB
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC} = \pm 9\ \text{V to } \pm 15\ \text{V},$ $V_O = 0, R_S = 50\ \Omega,$ $T_A = 25^\circ\text{C}$	70	95	80	95			dB
P_D Total power dissipation (each amplifier)	$V_O = 0, T_A = 25^\circ\text{C},$ No load	6	7.5	6	7.5			mW
I_{CC} Supply current (each amplifier)	$V_O = 0, T_A = 25^\circ\text{C},$ No load	200	250	200	250			μA
V_{O1}/V_{O2} Crosstalk attenuation	$A_{VD} = 100, T_A = 25^\circ\text{C}$	120			120			dB

† All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. Full range for T_A is 0°C to 70°C for TL06_C, TL06_AC, and TL06_BC and -40°C to 85°C for TL06_I.

‡ Input bias currents of an FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive, as shown in Figure 15. Pulse techniques are used to maintain the junction temperature as close to the ambient temperature as possible.



**TL061, TL061A, TL061B, TL062, TL062A
TL062B, TL064, TL064A, TL064B
LOW-POWER JFET-INPUT OPERATIONAL AMPLIFIERS**

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electrical characteristics, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS†		TL061BC TL062BC TL064BC			TL061I TL062I TL064I			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 0,$ $R_S = 50 \Omega$	$T_A = 25^\circ\text{C}$	2	3		3	6	mV	
		$T_A = \text{Full range}$			5		9		
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage	$V_O = 0, R_S = 50 \Omega,$ $T_A = \text{Full range}$		10			10		$\mu\text{V}/^\circ\text{C}$	
I_{IO} Input offset current	$V_O = 0$	$T_A = 25^\circ\text{C}$	5	100		5	100	pA	
		$T_A = \text{Full range}$		3			10	nA	
I_{IB} Input bias current‡	$V_O = 0$	$T_A = 25^\circ\text{C}$	30	200		30	200	pA	
		$T_A = \text{Full range}$		7			20	nA	
V_{ICR} Common-mode input voltage range	$T_A = 25^\circ\text{C}$		± 11	-12 to 15		± 11	-12 to 15	V	
V_{OM} Maximum peak output voltage swing	$R_L = 10 \text{ k}\Omega, T_A = 25^\circ\text{C}$		± 10	± 13.5		± 10	± 13.5	V	
	$R_L \geq 10 \text{ k}\Omega, T_A = \text{Full range}$		± 10			± 10			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V},$ $R_L \geq 10 \text{ k}\Omega$	$T_A = 25^\circ\text{C}$	4	6		4	6	V/mV	
		$T_A = \text{Full range}$	4			4			
B_1 Unity-gain bandwidth	$R_L = 10 \text{ k}\Omega, T_A = 25^\circ\text{C}$		1			1		MHz	
r_i Input resistance	$T_A = 25^\circ\text{C}$		10^{12}			10^{12}		Ω	
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0,$ $R_S = 50 \Omega, T_A = 25^\circ\text{C}$		80	86		80	86	dB	
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC} = \pm 9 \text{ V to } \pm 15 \text{ V},$ $V_O = 0, R_S = 50 \Omega,$ $T_A = 25^\circ\text{C}$		80	95		80	95	dB	
P_D Total power dissipation (each amplifier)	$V_O = 0,$ No load	$T_A = 25^\circ\text{C},$	6	7.5		6	7.5	mW	
I_{CC} Supply current (each amplifier)	$V_O = 0,$ No load	$T_A = 25^\circ\text{C},$	200	250		200	250	μA	
V_{O1}/V_{O2} Crosstalk attenuation	$A_{VD} = 100, T_A = 25^\circ\text{C}$		120			120		dB	

† All characteristics are measured under open-loop conditions with zero common-mode input voltage, unless otherwise specified. Full range for T_A is 0°C to 70°C for TL06_C, TL06_AC, and TL06_BC and -40°C to 85°C for TL06_I.

‡ Input bias currents of an FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive, as shown in Figure 15. Pulse techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

**TL061, TL061A, TL061B, TL062, TL062A
TL062B, TL064, TL064A, TL064B
LOW-POWER JFET-INPUT OPERATIONAL AMPLIFIERS**

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electrical characteristics, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONST	TL061M TL062M			TL064M			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 0$, $R_S = 50 \Omega$	$T_A = 25^\circ\text{C}$		3	6	$T_A = 25^\circ\text{C}$		mV
		$T_A = -55^\circ\text{C to } 125^\circ\text{C}$		9		15		
$\alpha_{V_{IO}}$ Temperature coefficient of input offset voltage	$V_O = 0$, $R_S = 50 \Omega$, $T_A = -55^\circ\text{C to } 125^\circ\text{C}$	10			10			$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current	$V_O = 0$	$T_A = 25^\circ\text{C}$		5	100	$T_A = 25^\circ\text{C}$		pA
		$T_A = -55^\circ\text{C}$		20*		20*		nA
		$T_A = 125^\circ\text{C}$		20		20		
I_{IB} Input bias current†	$V_O = 0$	$T_A = 25^\circ\text{C}$		30	200	$T_A = 25^\circ\text{C}$		pA
		$T_A = -55^\circ\text{C}$		50*		50*		nA
		$T_A = 125^\circ\text{C}$		50		50		
V_{ICR} Common-mode input voltage range	$T_A = 25^\circ\text{C}$	± 11.5	-12 to 15	± 11.5	-12 to 15			V
V_{OM} Maximum peak output voltage swing	$R_L = 10 \text{ k}\Omega$, $T_A = 25^\circ\text{C}$	± 10	± 13.5	± 10	± 13.5			V
	$R_L \geq 10 \text{ k}\Omega$, $T_A = -55^\circ\text{C to } 125^\circ\text{C}$	± 10		± 10				
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}$, $R_L \geq 10 \text{ k}\Omega$	$T_A = 25^\circ\text{C}$		4	6	$T_A = 25^\circ\text{C}$		V/mV
		$T_A = -55^\circ\text{C to } 125^\circ\text{C}$		4		4		
B_1 Unity-gain bandwidth	$R_L = 10 \text{ k}\Omega$, $T_A = 25^\circ\text{C}$							MHz
r_i Input resistance	$T_A = 25^\circ\text{C}$	10 ¹²			10 ¹²			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $V_O = 0$, $R_S = 50 \Omega$, $T_A = 25^\circ\text{C}$	80	86	80	86			dB
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC} = \pm 9 \text{ V to } \pm 15 \text{ V}$, $V_O = 0$, $R_S = 50 \Omega$, $T_A = 25^\circ\text{C}$	80	95	80	95			dB
P_D Total power dissipation (each amplifier)	$V_O = 0$, No load	$T_A = 25^\circ\text{C}$		6	7.5	$T_A = 25^\circ\text{C}$		mW
I_{CC} Supply current (each amplifier)	$V_O = 0$, No load	$T_A = 25^\circ\text{C}$		200	250	$T_A = 25^\circ\text{C}$		μA
V_{O1}/V_{O2} Crosstalk attenuation	$A_{VD} = 100$, $T_A = 25^\circ\text{C}$	120			120			dB

* This parameter is not production tested.

† All characteristics are measured under open-loop conditions with zero common-mode voltage, unless otherwise specified.

‡ Input bias currents of an FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive, as shown in Figure 15. Pulse techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

operating characteristics, $V_{CC\pm} = \pm 15$ V, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
SR Slew rate at unity gain (see Note 5)	$V_I = 10 \text{ V}$, $C_L = 100 \text{ pF}$, $R_L = 10 \text{ k}\Omega$, See Figure 1	C and I suffix		1.5	3.5	V/ μs
		M suffix		2	3.5	
t_r Rise time	$V_I = 20 \text{ mV}$, $C_L = 100 \text{ pF}$, See Figure 1	$R_L = 10 \text{ k}\Omega$, See Figure 1		0.2		μs
Overshoot factor				10%		
V_n Equivalent input noise voltage	$R_S = 20 \Omega$, $f = 1 \text{ kHz}$	42			nV/ $\sqrt{\text{Hz}}$	

NOTE 5: Slew rate at $-55^\circ\text{C to } 125^\circ\text{C}$ is 0.7 V/ μs min.



PARAMETER MEASUREMENT INFORMATION

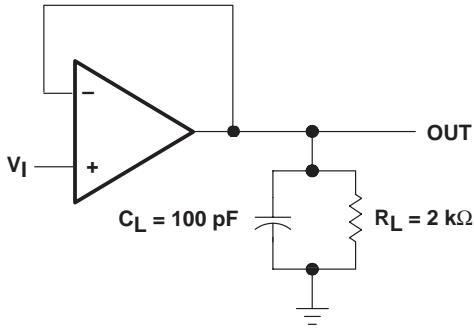


Figure 1. Unity-Gain Amplifier

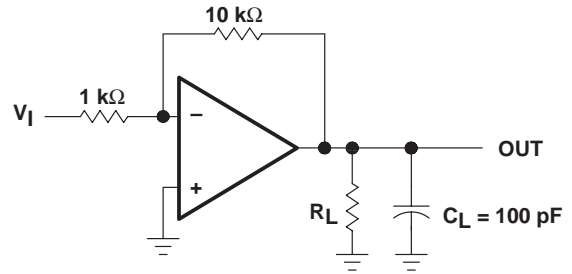


Figure 2. Gain-of-10 Inverting Amplifier

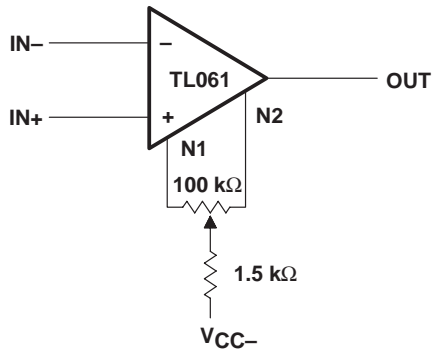


Figure 3. Input Offset-Voltage Null Circuit

TYPICAL CHARACTERISTICS

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TYPICAL CHARACTERISTICS†

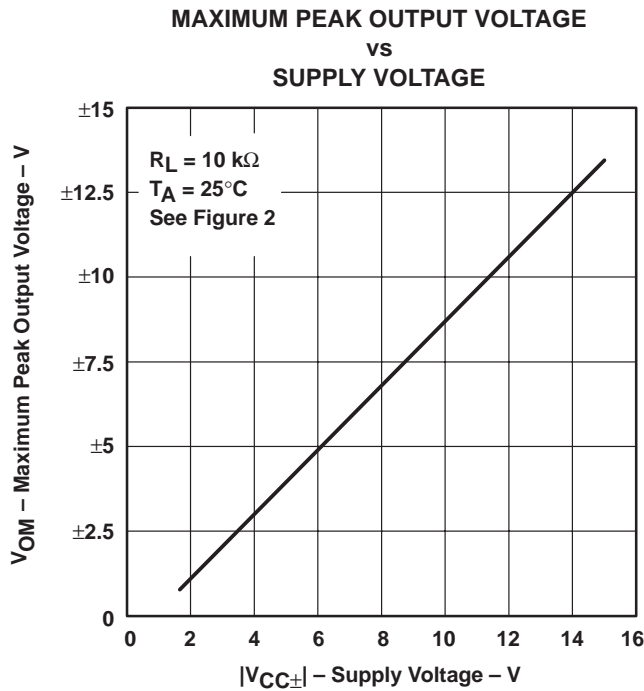


Figure 4

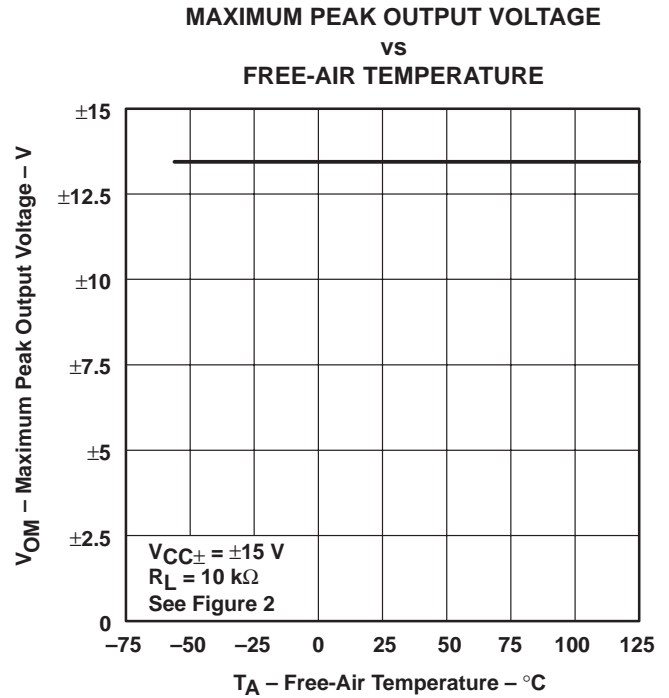


Figure 5

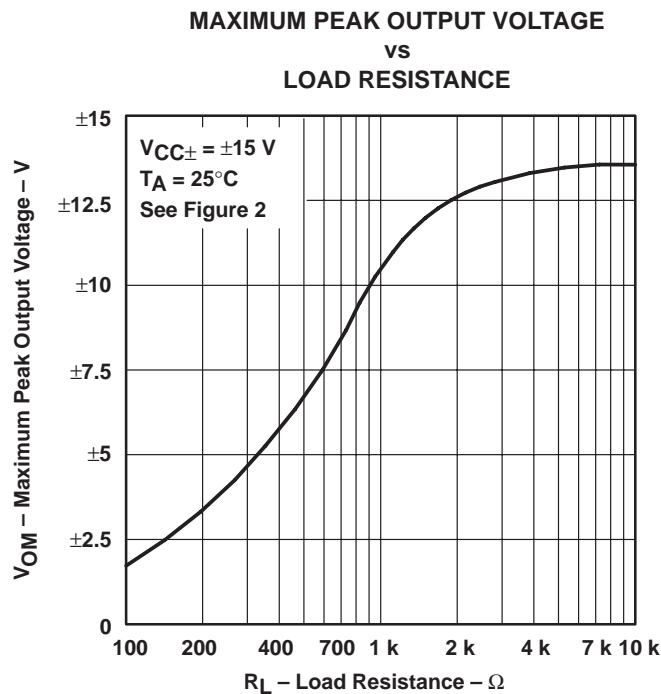


Figure 6

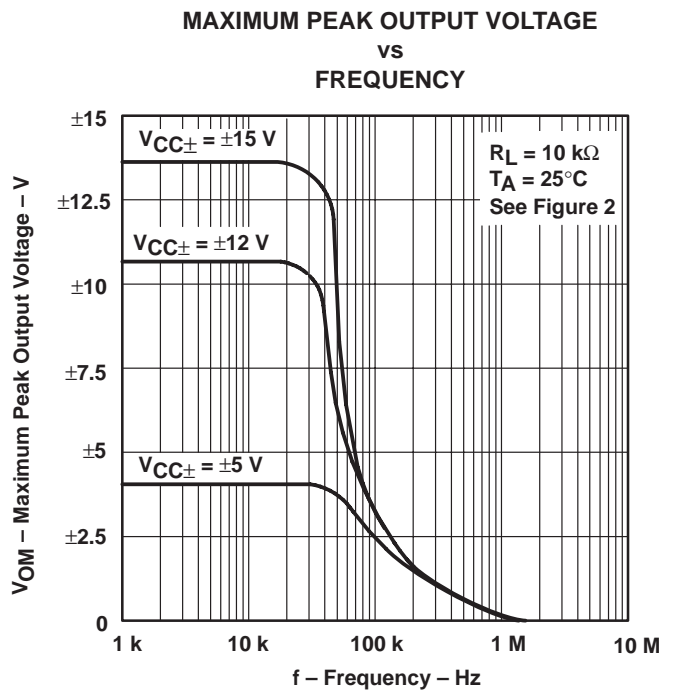


Figure 7

† Data at high and low temperatures are applicable only within the specified operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

DIFFERENTIAL VOLTAGE AMPLIFICATION
 VS
 FREE-AIR TEMPERATURE

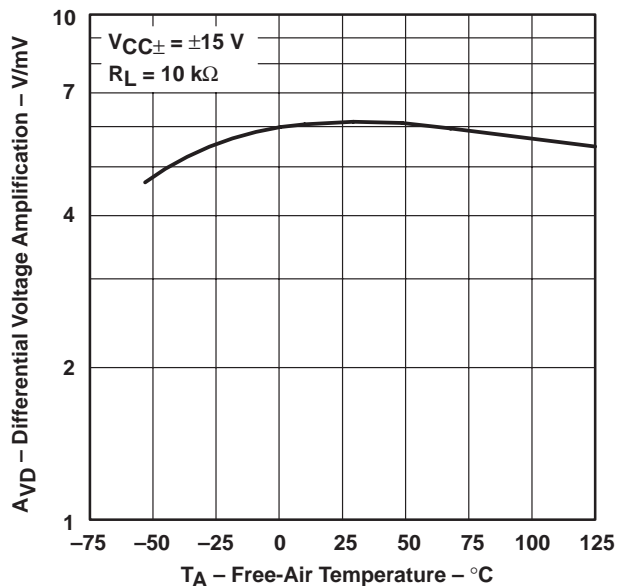


Figure 8

LARGE-SIGNAL
 DIFFERENTIAL VOLTAGE
 AMPLIFICATION AND PHASE SHIFT
 VS
 FREQUENCY

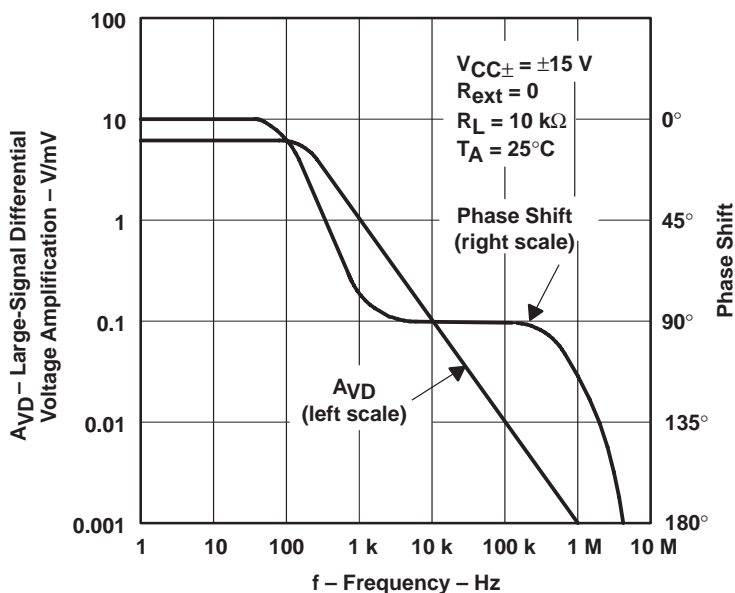


Figure 9

† Data at high and low temperatures are applicable only within the specified operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

SUPPLY CURRENT
 vs
 SUPPLY VOLTAGE

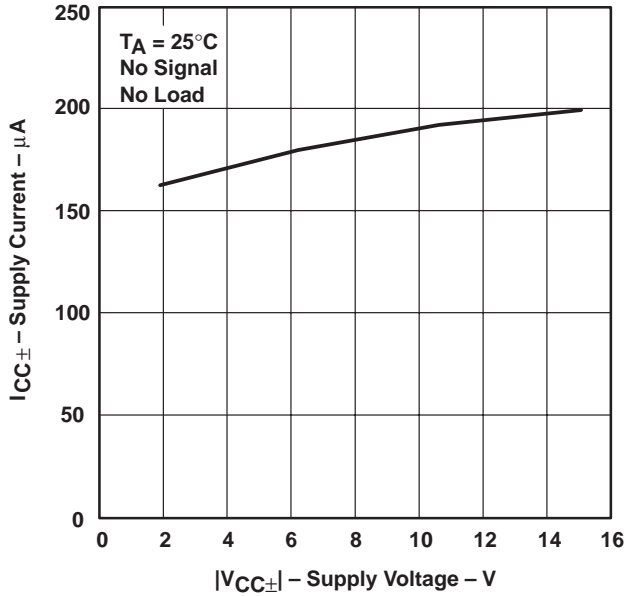


Figure 10

SUPPLY CURRENT
 vs
 FREE-AIR TEMPERATURE

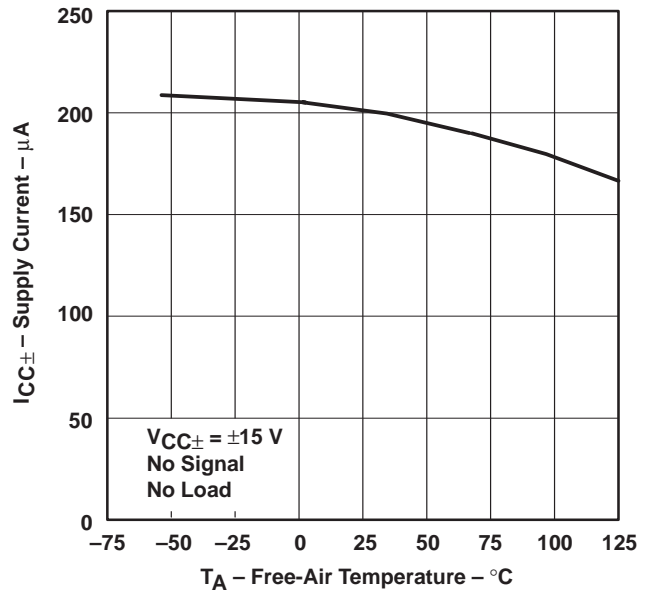


Figure 11

TOTAL POWER DISSIPATION
 vs
 FREE-AIR TEMPERATURE

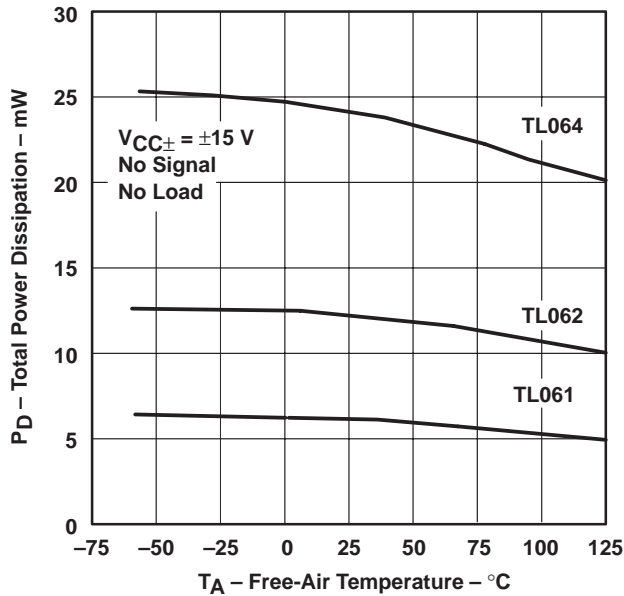


Figure 12

ALL EXCEPT TL06_C
 COMMON-MODE REJECTION RATIO
 vs
 FREE-AIR TEMPERATURE

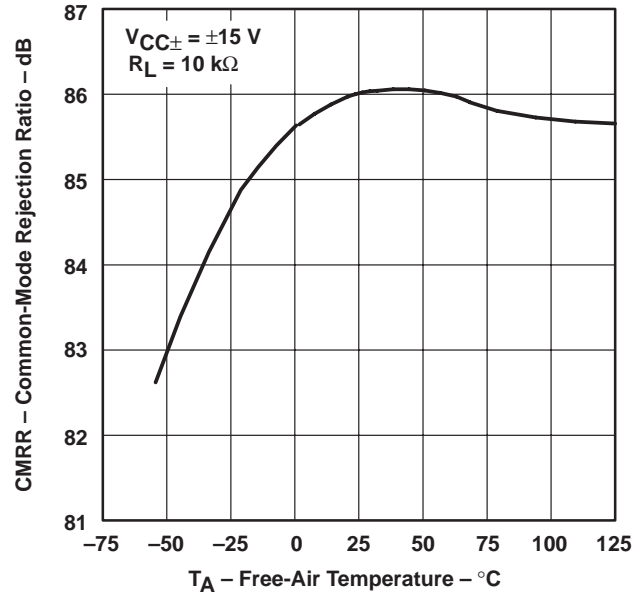


Figure 13

† Data at high and low temperatures are applicable only within the specified operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

NORMALIZED UNITY-GAIN BANDWIDTH,
 SLEW RATE, AND PHASE SHIFT
 vs
 FREE-AIR TEMPERATURE

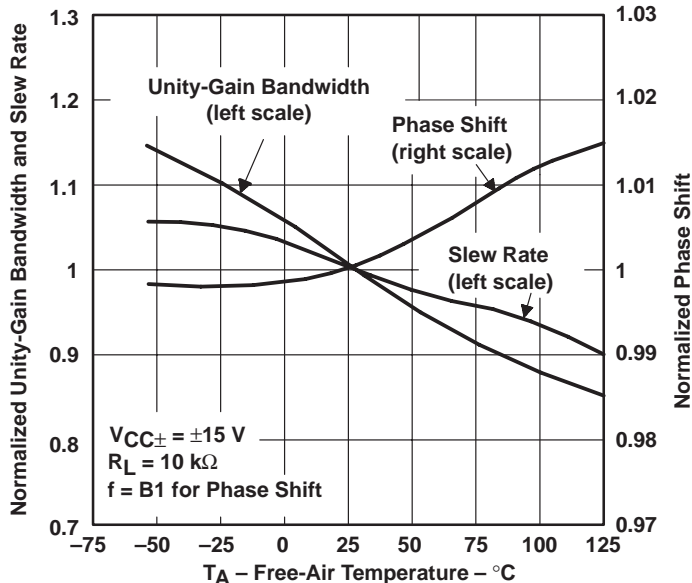


Figure 14

INPUT BIAS CURRENT
 vs
 FREE-AIR TEMPERATURE

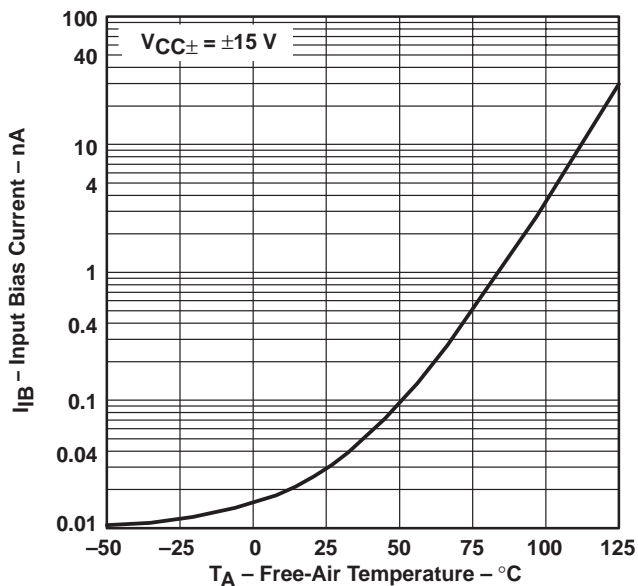


Figure 15

VOLTAGE-FOLLOWER
 LARGE-SIGNAL PULSE RESPONSE
 vs
 TIME

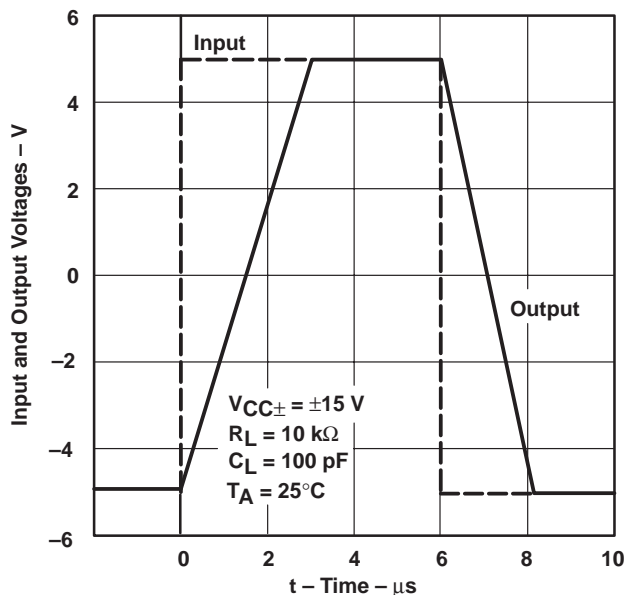
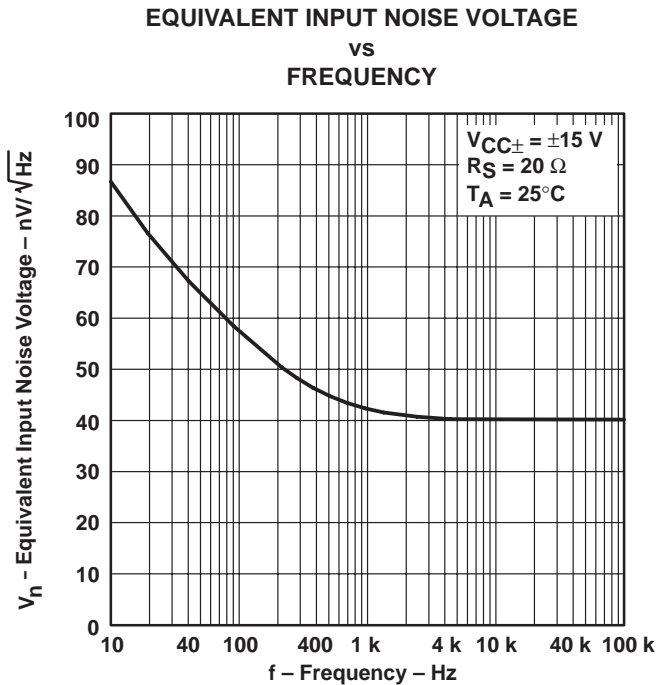
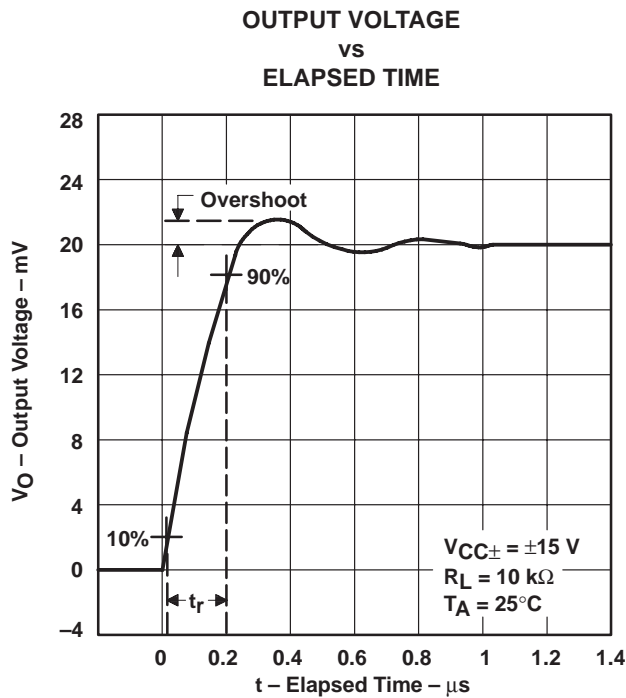


Figure 16

TYPICAL CHARACTERISTICS



APPLICATION INFORMATION

Table of Application Diagrams

APPLICATION DIAGRAM	PART NUMBER	FIGURE
Instrumentation amplifier	TL064	19
0.5-Hz square-wave oscillator	TL061	20
High-Q notch filter	TL061	21
Audio-distribution amplifier	TL064	22
Low-level light detector preamplifier	TL061	23
AC amplifier	TL061	24
Microphone preamplifier with tone control	TL061	25
Instrumentation amplifier	TL062	26
IC preamplifier	TL062	27

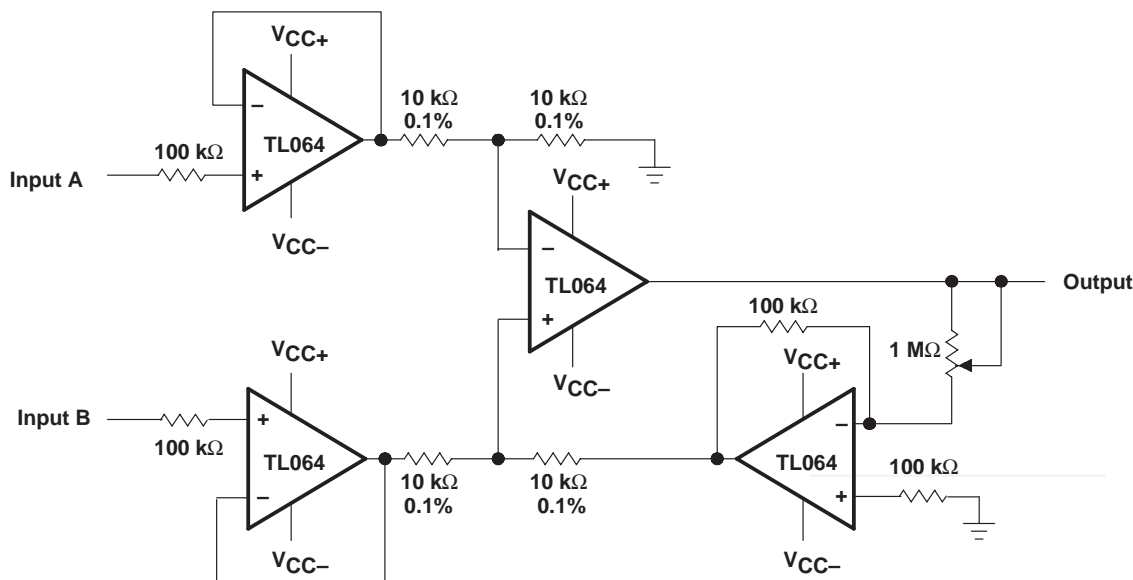


Figure 19. Instrumentation Amplifier

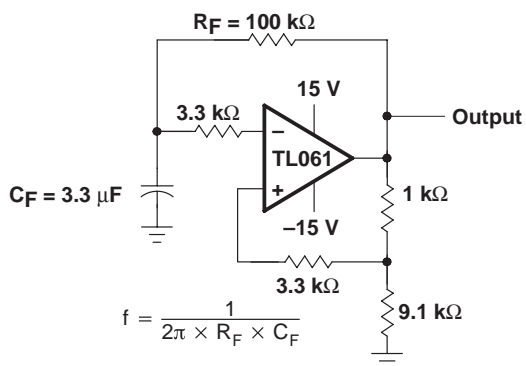


Figure 20. 0.5-Hz Square-Wave Oscillator

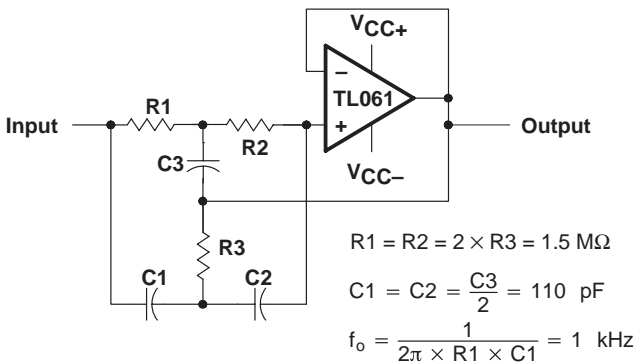


Figure 21. High-Q Notch Filter

APPLICATION INFORMATION

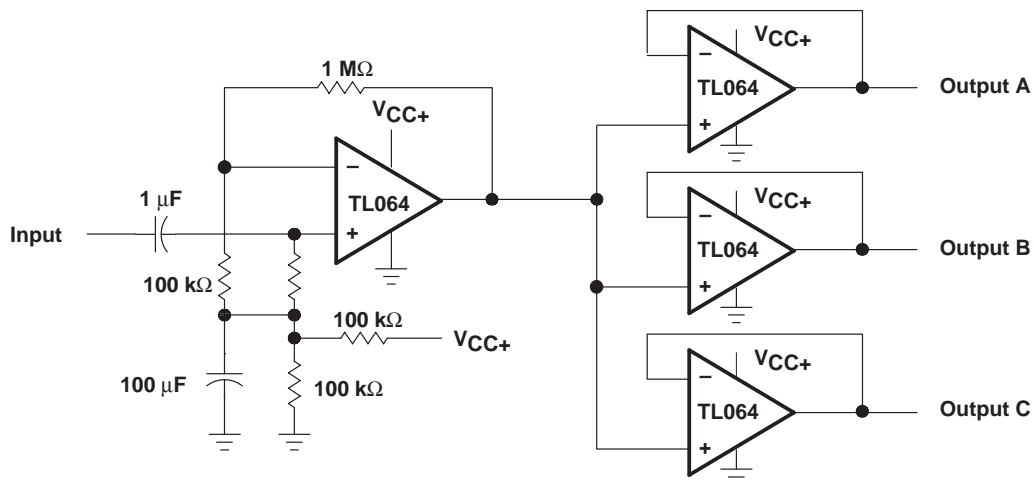


Figure 22. Audio-Distribution Amplifier

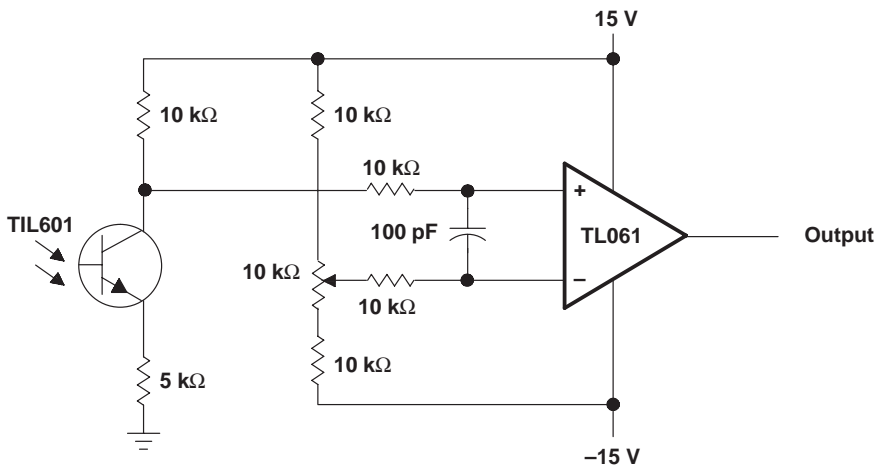


Figure 23. Low-Level Light Detector Preamplifier

APPLICATION INFORMATION

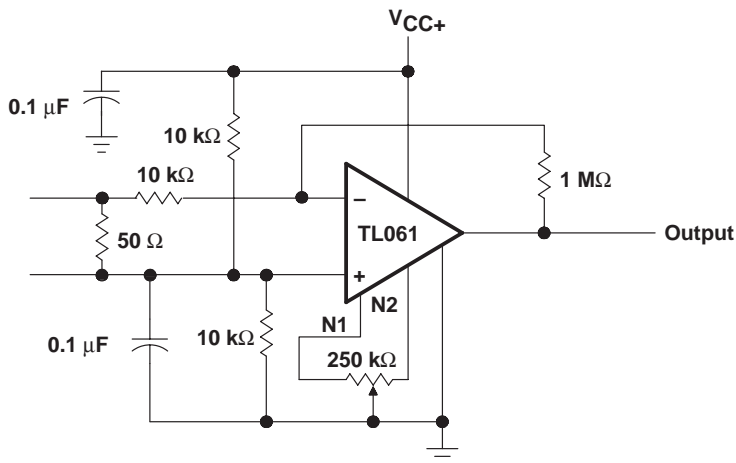


Figure 24. AC Amplifier

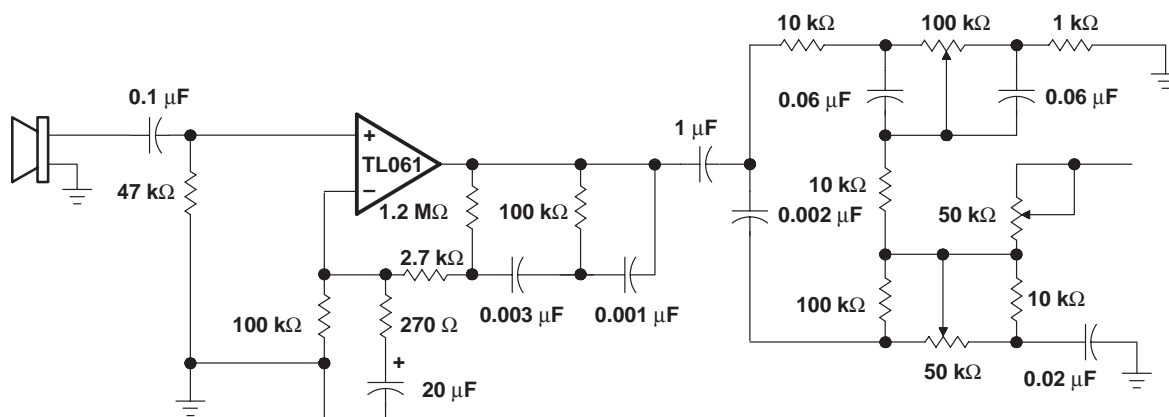


Figure 25. Microphone Preamp with Tone Control

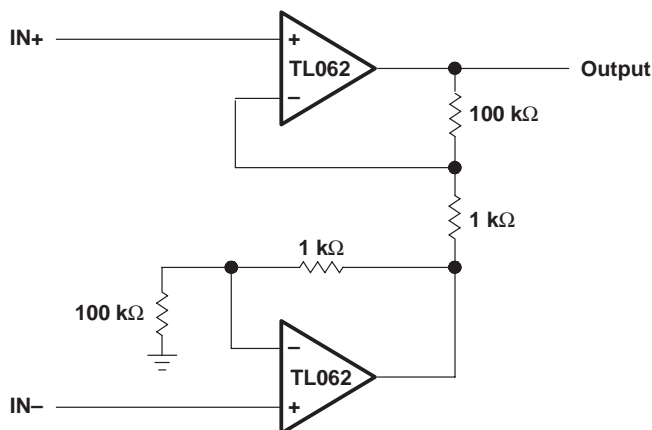


Figure 26. Instrumentation Amplifier

APPLICATION INFORMATION

IC PREAMPLIFIER RESPONSE CHARACTERISTICS

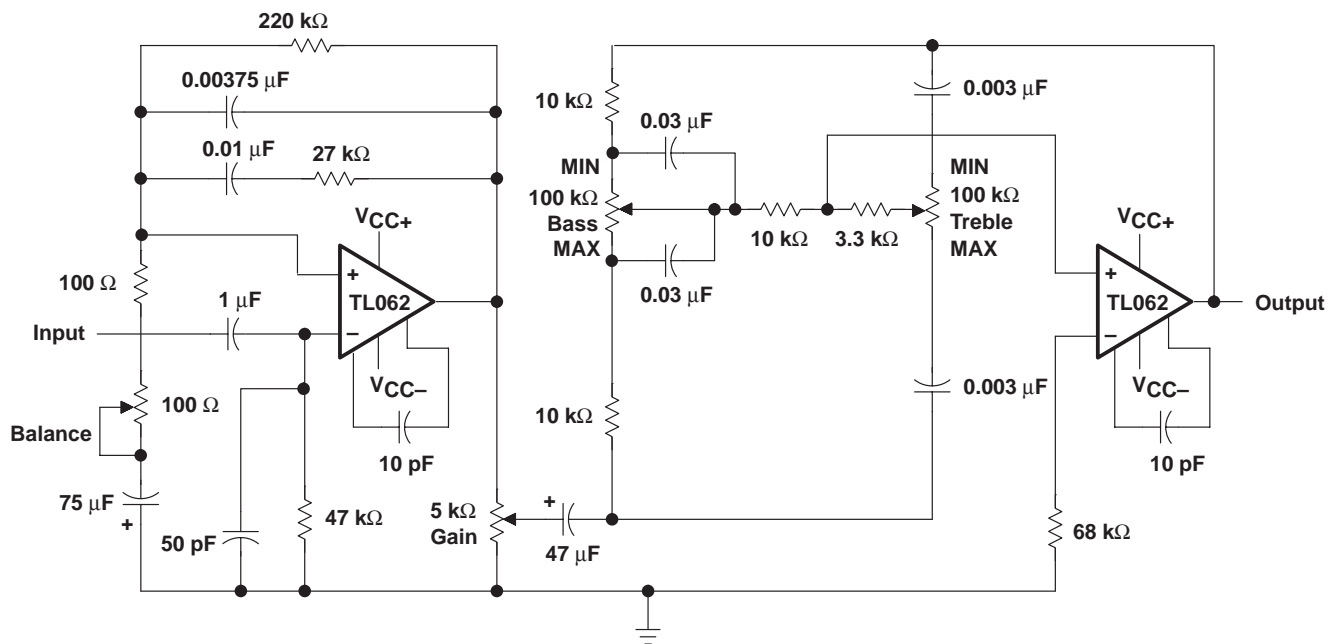
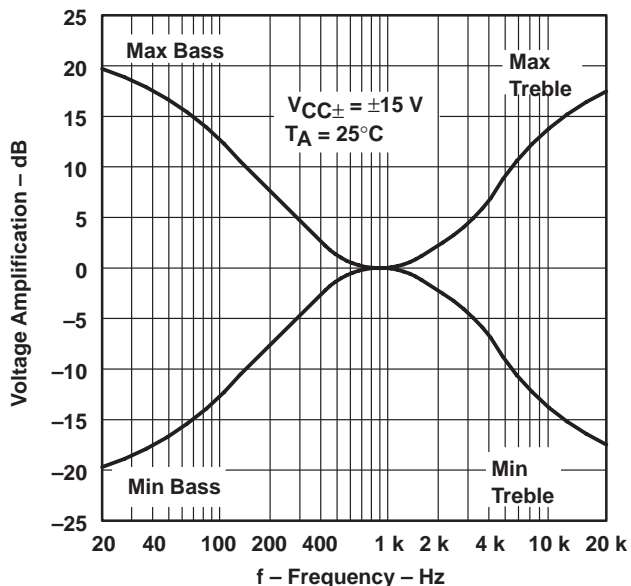


Figure 27. IC Preamplifier

JG (R-GDIP-T8)

CERAMIC DUAL-IN-LINE



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. This package can be hermetically sealed with a ceramic lid using glass frit.
 D. Index point is provided on cap for terminal identification.
 E. Falls within MIL STD 1835 GDIP1-T8

J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



DIM \ PINS **	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)

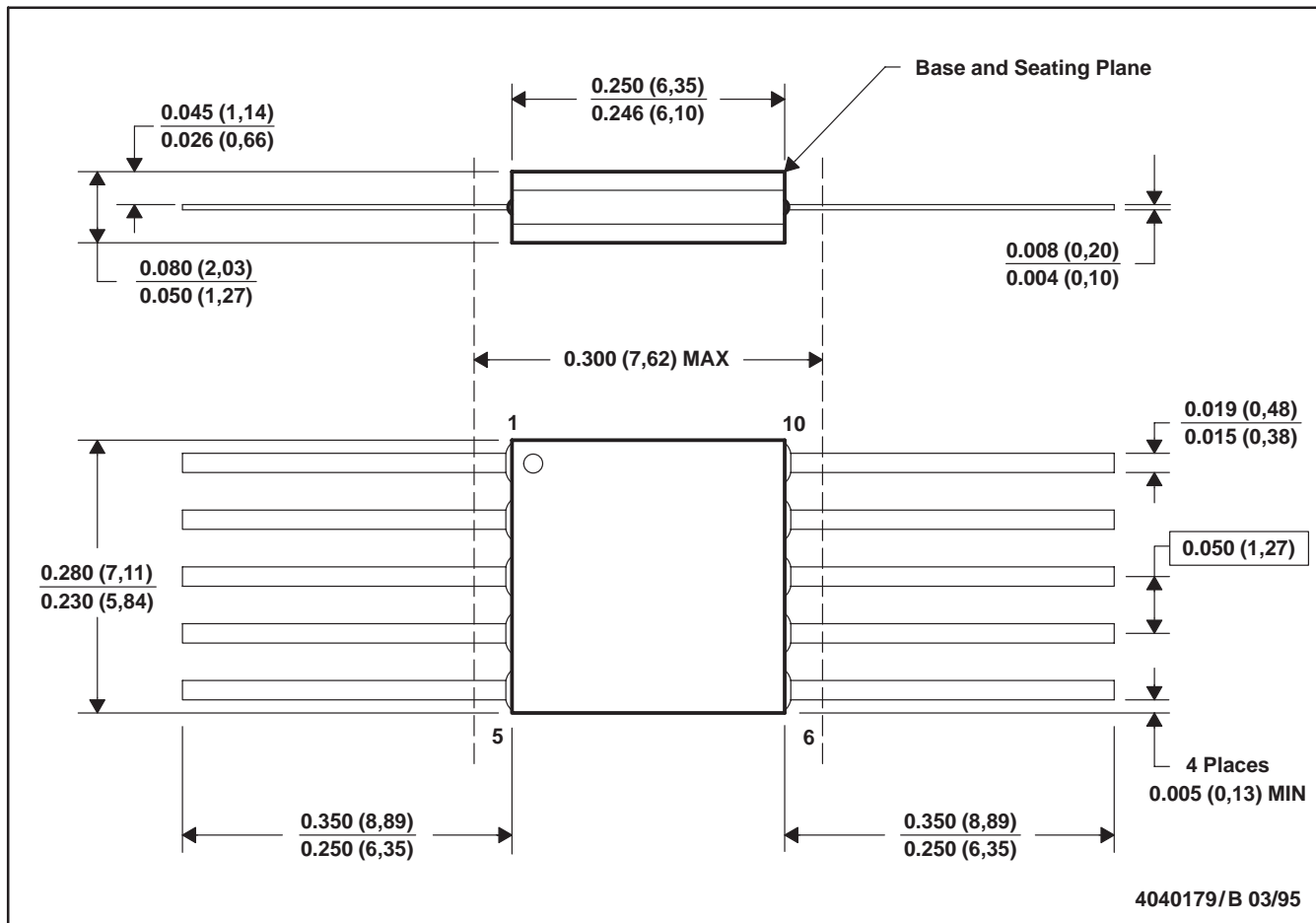


4040083/F 03/03

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package is hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

U (S-GDFP-F10)

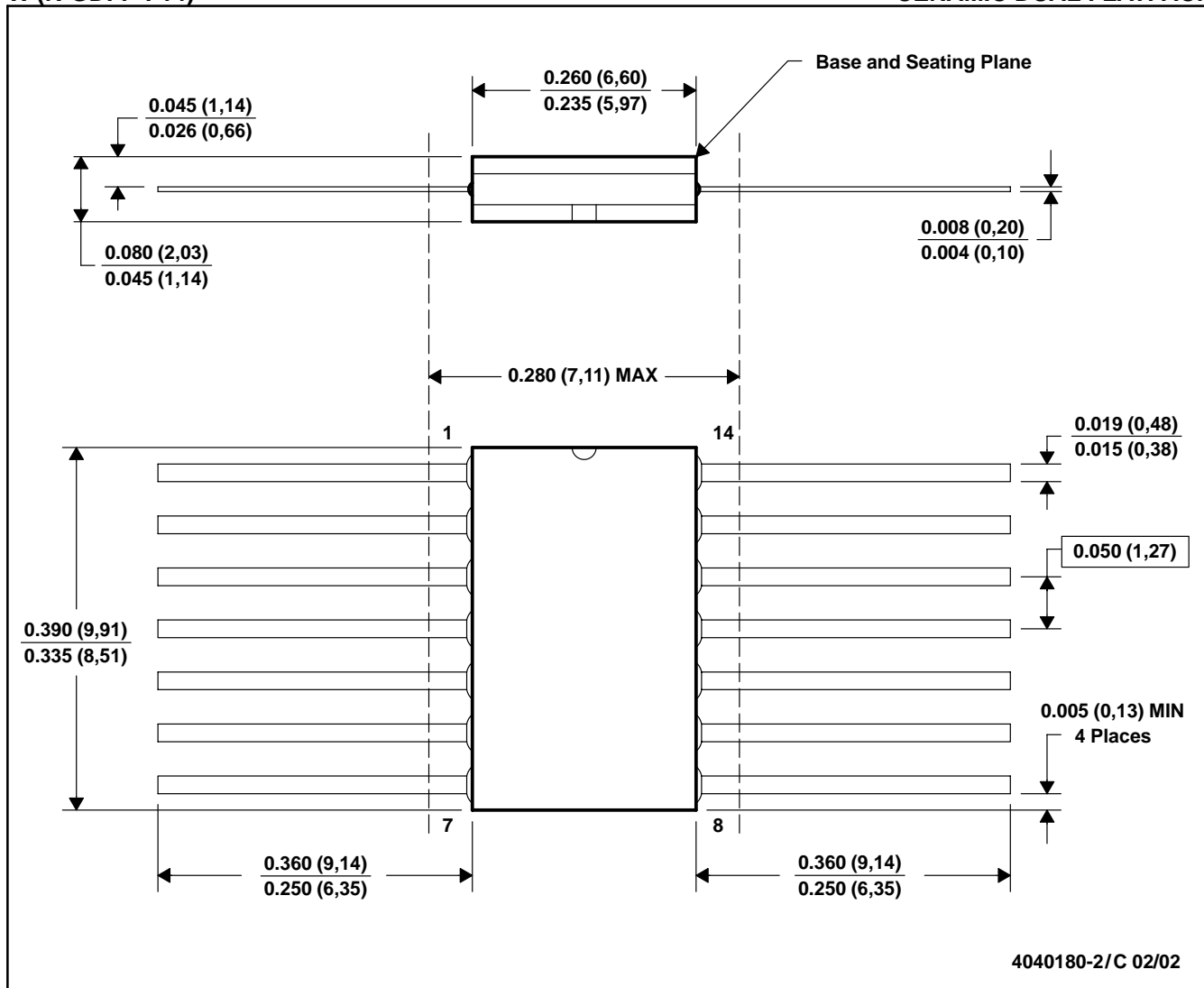
CERAMIC DUAL FLATPACK



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. This package can be hermetically sealed with a ceramic lid using glass frit.
 D. Index point is provided on cap for terminal identification only.
 E. Falls within MIL STD 1835 GDFP1-F10 and JEDEC MO-092AA

W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. This package can be hermetically sealed with a ceramic lid using glass frit.
 D. Index point is provided on cap for terminal identification only.
 E. Falls within MIL STD 1835 GDFP1-F14 and JEDEC MO-092AB

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a metal lid.
 - D. The terminals are gold plated.
 - E. Falls within JEDEC MS-004

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE



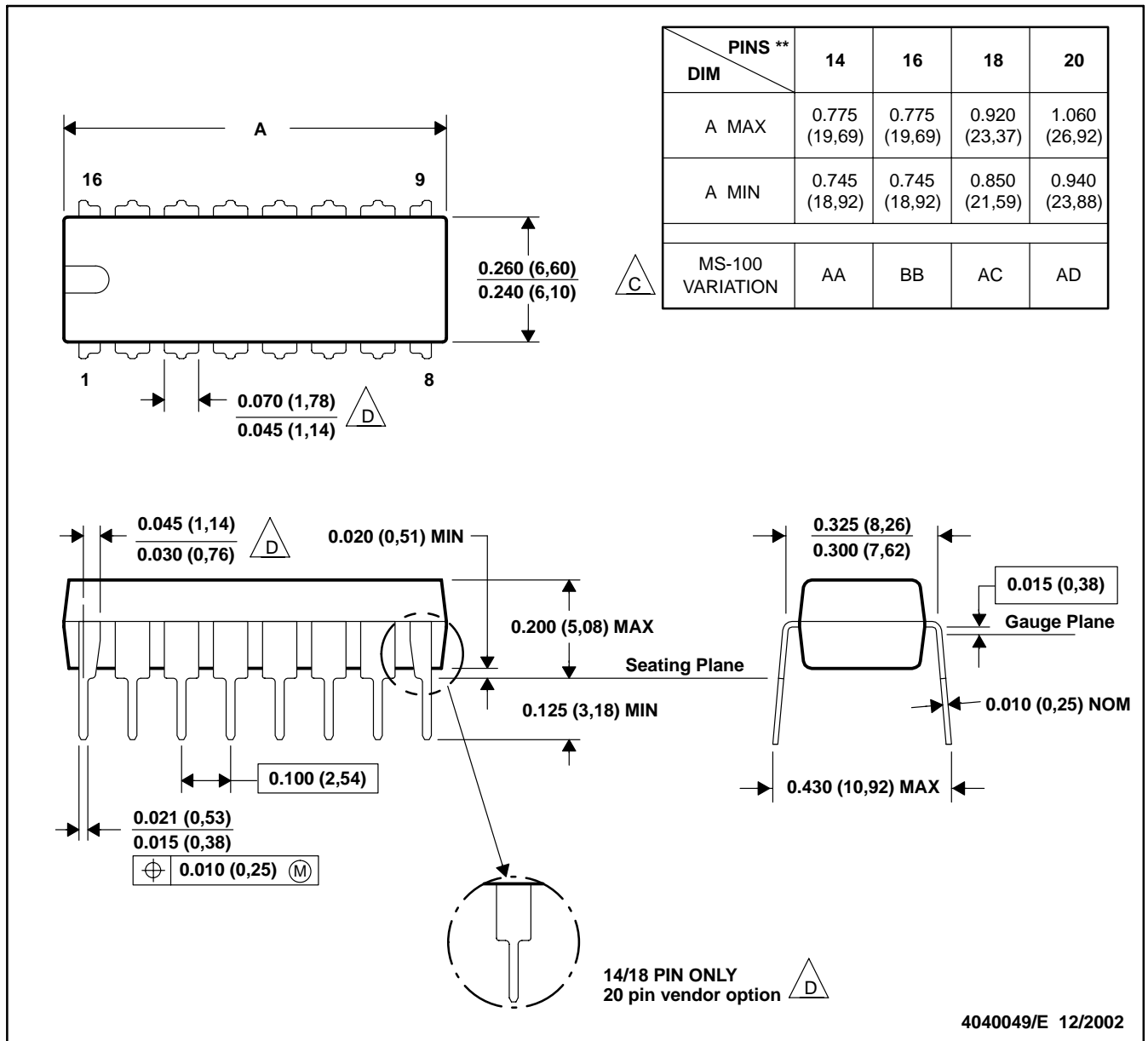
- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Falls within JEDEC MS-001

For the latest package information, go to http://www.ti.com/sc/docs/package/pkg_info.htm

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 (C) Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 (D) The 20 pin end lead shoulder width is a vendor option, either half or full width.

D (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

8 PINS SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).
 D. Falls within JEDEC MS-012

MECHANICAL DATA

PS (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

MECHANICAL DATA

NS (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



4040064/F 01/97

- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
 D. Falls within JEDEC MO-153

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